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Semiconductor Measurement Technology:

Version 2.0 of the TXYZ Thermal Analysis Program: TXYZ20

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John Albers

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Version 2.0 of the TXYZ Thermal Analysis Program: TXYZ20

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Abstract

The TXYZ computer program has been used for a number of years for the thermal analysis of semiconductor devices and packages. This program makes use of the closed form, Fourier series solution of the steady-state heat flow equation for the general case of a rectangular three-layer structure with multiple heat sources on the top surface. TXYZ provides for the calculation of the temperature at any set of points in this structure and has proven useful for the determination of the steady-state temperature distribution of semiconductor chips and packages. This report presents TXYZ Version 2.0 (TXYZ20) which is a revised and updated version of the original TXYZ program. The TXYZ20 program incorporates more flexible handling of input data, assignment of positive or negative noninteger weights to the various heat sources or heat sinks, and improved evaluation of limiting forms in the code.

The first part of this report consists of a discussion of the general elements in the TXYZ code and the particular changes which have been made to it to obtain TXYZ20. The second part of the report contains a discussion of several examples of the running of the code. Several annotated input data files are presented and discussed to show both the increased flexibility of the input data and the actual use of the updated code. Running the TXYZ20 code for one of the input files provides a benchmark for several machines. The user may wish to run this example for the purpose of comparing the CPU times involved. The appendix contains an annotated, internally documented listing of the FORTRAN source code for TXYZ20.

The FORTRAN source code (total of about 21 kbytes) and sample input and output data files are available in ASCII format using a number of transfer vehicles. These include: standard 8-track magnetic tape (ASCII, density = 1600, record = 80, block = 1600), 5.25-in. (360-kbyte and 1.2-Mbyte) DOS-formatted floppy disks, and electronic mail over the Internet. The sample input and output data files are included so that the user can check the program for proper operation as well as to become acquainted with the setup and use of the code. Users of the TXYZ code will find the updated TXYZ20 code easy to use and should benefit from the more flexible input and the more general treatment of heat sources and heat sinks.

Key words: FORTRAN; Fourier analysis; integrated circuit; semiconductor devices; semiconductor materials; steady-state heat flow; thermal analysis; thermal conductivity.

Introduction

The operation of a semiconductor device relies on the passage of current through portions of the structure. This is accompanied by power dissipation and heating which gives rise to a temperature distribution. In time, thermal stresses may arise and lead to device degradation and possible failure. In addition to the effects of thermal stresses on device reliability, the modeling of the steady-state thermal response of a system is also useful since the temperature distribution may have an effect upon the local mechanical, thermal, electrical, or optical properties of the system. Consequently, an accurate physical model of the temperature distribution under the power condition of actual operation is of great importance. It is also possible to ascertain the relative effects of composition (thermal conductivity) and geometry (layer thickness). By carefully optimizing composition and geometry, it may be possible to minimize the thermal stress and hence ensure optimal device lifetime.

The physical and mathematical model used here is taken from the work of Kokkas [1]. This has been used previously to construct the TXYZ program. The Kokkas model and the TXYZ code have been described in considerable detail in NBS Special Publication 400-76 [2]. This report is available and should be consulted for the details of the analysis which are still current and valid.

Review of the Model, the TXYZ Code, and the TXYZ20 Code

For the purposes of providing a background for the TXYZ20 code, a brief outline of the salient features of the earlier report on TXYZ is presented here. It is assumed that the reader has a copy of reference [2]. The symbols used here are defined in this reference. The outline presented here should provide the reader with an overview of the analysis and a quick guide as to where to find the various portions of the calculation.

The starting point of the calculation is the steady-state heat flow equation for a single rectangular layer. In Cartesian coordinates, this takes on the form

$$abla^2 T(x,y,z) = iggl\{ rac{\partial^2}{\partial x^2} + rac{\partial^2}{\partial y^2} + rac{\partial^2}{\partial z^2} iggr\} T(x,y,z) = 0.$$

This equation is solved in this coordinate system using Fourier analysis. The requirement that there be no heat transport out of the lateral boundaries of the structure leaves only "quantized" cosine functions in the Fourier representation of the temperature,

$$T(x,y,z) = \sum_{n=0}^{\infty} \sum_{m=0}^{\infty} \frac{4\tau(n,m,z)\cos(n\pi x/L_x)\cos(m\pi y/L_y)}{(\delta_{n0}+1)(\delta_{m0}+1)L_xL_y},$$

where $\delta_{nn'}$ is the Kronecker delta and is equal to unity if n = n' and zero otherwise.

The Fourier coefficients, $\tau(n, m, z)$, are given by

$$au(n,m,z) = lpha \cosh(\gamma z) + eta \sinh(\gamma z),$$

where the coefficients α and β , which may be functions of γ , are determined from the two z-dependent boundary conditions.

The above analysis provides the basis for the general multiple-layer problem in terms of the Fourier coefficients. For this case, it is assumed that the temperature satisfies the steady-state equation in each of the layers. Consequently, in each of the layers, the Fourier expansion of the temperature takes the form

$$\tau_i(n, m, z) = \alpha_i \cosh(\gamma z) + \beta_i \sinh(\gamma z), (i = 1, ..., n).$$

For each layer, there are two coefficients which arise from the fact that the basic temperature equation is second order. These are determined from the z-dependent boundary conditions. The general set of z-dependent boundary conditions for the multiple layer problem is provided by the conditions that: heat enters (or leaves) the structure through the portions of the top layer where power is applied, the temperature and the heat flow are continuous across the internal interfaces, and the temperature is continuous across the interface between the bottom layer and the heat sink. The above equations and boundary conditions provide the mathematical framework in which the multiple layer problem may be solved. For the purposes of numerical modeling, the multiple layer problem is specialized to one with three layers. In this case, the Kokkas [1] analysis leads to the solution in the form

$$T_i(x,y,z) = P_0 \sum_{n=0}^{\infty} \sum_{m=0}^{\infty} \frac{4U(n,m)\tau_i(n,m,z)\cos(n\pi x/L_x)\cos(m\pi y/L_y)}{(\delta_{n0}+1)(\delta_{m0}+1)L_xL_y\kappa_1}.$$

The symbols, analysis and particular forms of $\tau_i(n,m,z)$ are discussed in some detail in reference [2]. There are several parts of the above equation which can be identified. First, there is the z-dependent part of the solution in each layer, $\tau_i(n,m,z)$. The two cosine functions, $\cos(n\pi x/L_x)\cos(m\pi y/L_y)$, arise from the x- and y-dependent parts of the steady-state equation. Their specific form arises from the requirement of the lateral boundary conditions. Finally, the requirement that heat enters or leaves the top surface only through the heating elements introduces the function $P_0U(n,m)$. It should be noted that P_0 appears only in front of the sum. It is a scale or multiplicative factor which for convenience may be set equal to unity. Its effect is to scale the temperature in a direct linear fashion. Performing the calculation for $P_0 = 1$ for a given structure then provides the temperature distribution for arbitrary P_0 which can then be obtained by multiplying by the P_0 which is used.

In the above, the function, U(n, m), is related to the heat sources (sinks) on the top surface of the structure. This function is defined as the double cosine transform of the geometric part of the surface power function, U(x, y),

$$U(n,m) = \int_0^{L_x} \int_0^{L_y} U(x,y) \cos(n\pi x/L_x) \cos(m\pi y/L_y) dx dy.$$

The detailed form of this function is considered in reference [2]. There, the relation of this function to the location and size of the heat sources was presented. In addition, the

limiting form of the function as either n or m approach zero was considered, and the correct limit was established for the purposes of numerical analysis. The reader is referred to that report for details.

In the original version of TXYZ, all heat sources had equal unit weights. If the user wanted to construct a more general heat source, this could only be done in unit increments by superimposing sources. Hence, to perform the calculation for a heating element which had five times the effect as another, the element would have to constructed five times. Only integer increments were possible. The first change made in TXYZ is the generalization of the heating elements. It should be noted that this does change the basic model. The updated TXYZ20 program allows for noninteger weights to be assigned to each heating element. This weight may be positive or negative and hence represent the effects of either a heat source or a heat sink. The weight is entered through the input data file and appears with the location and size of the element. The reader should refer to the last lines in the input data files presented in tables 1, 4, 5, and 7 for the use of weighting of the heat elements. The more general information is then passed from the main program to the UZERO function through a COMMON statement. The weighting of the heating element was used originally in a calculation of the thermal interactions between electromigration test structures [3]. The careful and consistent evaluation of the temperature is important in this case as the test structures are used in accelerated testing and the temperature profile generated by one of the elements may increase the temperature at adjoining elements which may accelerate the failure rates. As electromigration is temperature dependent, it is of central importance to evaluate the temperature. This is especially the case where the thermal interaction of neighboring heating elements comes into play.

The weight is entered on the same line of the input data file where the position and lengths along x and y are entered. Instead of having to enter the same element five times, a weight of 5 may simply be used. In addition, noninteger weights which are positive or negative may be entered to represent sources or sinks. This feature should increase the versatility of the code to a more general class of problems.

Returning to the overview of the original TXYZ code and the basis for the evolution of TXYZ20, the behavior of the Fourier coefficients for both small and large values of the arguments is next on the agenda. The importance of this aspect of the analysis and the resulting numerical code is found in the fact that the equations involved contain the possibility of numerical infinities or overflow situations. These occur for n=0 and m=0 as well as for large values of these summation variables. The reason for the relatively compact nature of the original TXYZ code and its numerical efficiency is that great care was exercised in the investigation of the functions for the small and large argument regime. For small values of the argument, the evaluation of limiting forms led to expressions which were correct and free of artificial numerical singularities. For large values of the argument, special care was required. Many of the functions involved contained the hyperbolic sinh and cosh functions. These approach the exponential function for large values of the argument. These provide the possibility for numerical infinities or overflows. Careful investigation of the forms of the functions showed that these numerical infinities were removable by

other numerical infinities. For example, an exponential in the numerator and denominator of a function would give rise to two overflows when evaluated by a computer but would cancel each other and give rise to a finite result when analytic evaluation was properly applied. The construction of the function, FUNZ, in the TXYZ code was based upon such evaluations and their numerical implementations. With the passage of time and the use of the TXYZ code, one place where such cancellation was found to be incomplete was in the case of a fairly thick middle layer. For most cases of interest to the modeling of the steady-state thermal response of semiconductor device structures, these layers are usually thin. However, this situation has now been carefully investigated and the numerically stable limiting form has been determined and used in the code in the middle layer portion of the FUNZ function. The introduction of the nonsingular limiting form is contained in the TXYZ20 code.

The original TXYZ report contains a section showing how the one-dimensional equations are obtained in the special case of a power source which completely covers the top surface. This analysis requires the careful evaluation of limits. When properly applied, the one-dimensional expressions for the thermal resistance are obtained. The reader is referred to reference [2] for the details.

The last item to discuss before addressing the structure of the input data file for TXYZ20 is concerned with the effect of the upper summation limits on the calculated temperature. While this is discussed on pp. 32-33 and in figure 7 of reference [2], it is an important concept to understand and utilize correctly when running the code. Consider the case of a structure with lateral dimension of L and a heat element of lateral dimension of Δ . For the Fourier series to begin "seeing" this element, the cosine function in the basis set must have at least one complete cycle in Δ . As the element is rectangular, one cycle is certainly not enough, as the cosine is a poor representation of the rectangle. Consequently, higher "frequencies" are in order to assure the adequacy of the representation. The rule of thumb is that the number of terms should be at least on the order of L/Δ . A stronger rule of thumb would require several times the above rule of thumb. Certainly, the example of reference [2] for $L/\Delta = 200$ shows that the asymptotic value of the temperature is attained for 400 to 500 terms. In general, the stronger rule of thumb should be applied to the smallest heat element in order to achieve better accuracy.

In its present form, TXYZ20 allows an upper limit of 500 terms. With smaller feature sizes, this upper limit may be inadequate. If this is the case, it is important to edit the FORTRAN source code for TXYZ20. This requires the following changes. First, the DIMENSION statements in the main program for COSTY(500), ARUZER(500,500) and ARFUNZ(500,500) must be increased. Second, the line which tests the input values of the two upper limits and stops execution of the program if they are too big must be turned off. The evolution of computers over the past decade has put more memory in the hands of the user. Increasing the size of the DIMENSION statements may just test the extent of this memory. Failure of the modified code to compile due to memory restrictions is the test.

A note of caution is in order here. If the test line is turned off and the upper limit is larger

than the size of the DIMENSION statement, the calculation will proceed with values being stored in incorrect registers. No meaning should be ascribed to the results. Of course, the author is available for discussion and advice.

Examples of Calculations with TXYZ20

This portion of the report is concerned with examples of the input data file for the TXYZ20 code. The reader is encouraged to read through the listing of the FORTRAN source code for TXYZ20. In regard to the input data, special attention should be given to the internal documentation which is provided in the portion which describes the input section (see pp. 21-22). The variables and their use as well as the form of their input are all described in considerable detail there. Before describing the changes in the input data files, a special note is in order concerning the units used in the calculations. It is of utmost importance that the various input parameters be in a consistent set of units. Whatever length unit is used for the dimensions of the structure, the dimensions of the heat elements and the layer thicknesses must also be used in the thermal conductivities and the power density. Hence, if length is used for the former, then the thermal conductivities must be in the units of watts/ °C length and the power density must be in the units of watts/(length)².

The major changes in the input have to do with (1) the input or generation of the x, y, and z values to be used and (2) the input of the weighting factor for the heating elements. These are discussed in some detail here.

The input for the x, y, and z values has been made more flexible and consistent. As the treatment of each of these is the same, discussion will be focused on only the first.

The first five lines of the input data file remains the same as that used in the original TXYZ code. These contain the dimensions of the rectangular structure, the thickness, and thermal conductivity of the three layers and the summation limits for the double sum. The sixth line contains the integer index, IEDGEX. This is used for the generation or input of the values of x to be used in the calculation. If IEDGEX = 1, then a set of equispaced values of x will be generated. For this case, the next line of the input data file is to contain three numbers. These are: ILX (the number of x values to be generated), X1 (the value of the first x point), and STEPX (the value of the increment in x). Once these numbers are read in, the program constructs the set of points according to

$$X(I) = X1 + (I-1)*STEPX (I=1,...,ILX).$$

If IEDGEX = 2, then a set of values of x will be read from the data file. For this case, the the next line of the input data file will contain the number of x values to be read, ILX. The program will then read in ILX lines of input data file containing one value of x for each line. The IEDGEX = 2 option allows for the calculation to be performed at a set of x values which are not necessarily equispaced. This is particularly useful if the user wants to have some of the x values closely spaced on or near a heat element and other values spread out away from the heat element. This option is motivated by the fact that the temperature is usually rapidly varying near the element and slowly varying away from it.

Once the values of x have been generated or read, the code goes on to generate or read the values of y and then to generate or read the values of z by the same construction. As noted in the source code internal documentation (see pp. 21-22), the information on the generation or reading of the z values is always entered as positive quantities. The code takes care of making the appropriate sign changes.

The other major change in the input data file is the introduction of the weighting factor for each heat element. Once the number of heat elements has been read in along with the power density, the information for each of the heating elements is then read. For each element, a single line of five numbers contains all of the information. The weighting factor is the first entry on the line. Hence, the line contains WTSOUR(I), XSOUR(I), YSOUR(I), LXSOUR(I), AND LYSOUR(I). WTSOUR(I) is the weighting factor (positive for source, negative for sink) for the i-th element. This is a REAL number and does not have to be INTEGER.

The above features make the structure of the input data file more flexible and consistent. It is important to note, as has been discussed before, that the power density variable, P_0 , be set equal to unity. In effect, the calculation then generates a scaled temperature, $T(x,y,x)/P_0$, which may always be rescaled for a particular value of P_0 .

Before turning to the examples, it is also important to note the changes made in the output data file. The format used for the construction of the output data is of a general nature. It has been written to accommodate a wide range of numerical values without loss of generality or data. This was motivated by the fact that datum may be lost on output if it exceeds the format of the write statement. In order to circumvent this, the data may appear to have more significant figures than might be reasonable or needed. The user should keep this in mind when looking at the output. The user should round the output following accepted rules for this process. All the WRITE statements in the FORTRAN source code direct output to logical device for 012. The one exception is the line which is written if either one or both of the upper summation limits exceeds the dimensionality of the arrays used. This terminates program execution. Assuming that this is not the case, the data which are written to for012 are x, y, z, T(x,y,z). The major loop in the code (3000) is involved with the various z values used. Once the list of x, y, and z values for the calculations of T(x,y,z) has been completed, the remaining section of the output data file contains the listing of the input variables used in the calculations. Saving the output data without some identifier of the input data can present problems as to where the output came from. This is taken care of with the present listing to for012.

Benchmark Example

The first example is contained in the two files, input1.dat and output1.dat. This is for the case of a single heat source of unit weight. The temperature is calculated for 11 values of x. The example is illustrative of the use of the TXYZ20 code. The reader is referred to the annotated input and output data files (see tables 1 and 2) where each line of the file is described. This particular problem is of interest as it requires a small amount of time to carry out but does provide for some indication of the relative speeds which users can

Table 1. Annotated input data file (input1.dat) for TXYZ20 code.

The data correspond to those contained in the file input1.dat which can be used to run the case of a single heat source of unit weight. This illustrates the use of the IEDGEX = 1 generation of a set of values of x to be used in the calculation. In this and subsequent annotated input data file listings, it is important for the user to keep in mind the comments of p. 6 regarding the consistency of the units to be used in the calculation.

INPUT DATA	DESCRIPTION OF INPUT DATA
100 100	X AND Y DIMENSIONS OF RECTANGULAR STRUCTURE
1 .001	THICKNESS AND THERMAL CONDUCTIVITY OF TOP LAYER
5 .0001	THICKNESS AND THERMAL CONDUCTIVITY OF MIDDLE LAYER
4 .005	THICKNESS AND THERMAL CONDUCTIVITY OF BOTTOM LAYER
500 500	UPPER SUMMATION LIMITS FOR N AND M SUMMATIONS
1	IEDGEX (=1, THEN READ IN THREE VALUES ON NEXT LINE)
11 0.0 10.	NUMBER OF VALUES, FIRST POINT, INCREMENT
1	IEDGEY (=1, THEN READ IN THREE VALUES ON NEXT LINE)
1 50. 0.0	NUMBER OF VALUES, FIRST POINT, INCREMENT
1	IEDGEZ (=1, THEN READ IN THREE VALUES ON NEXT LINE)
1 0.0 0.0	NUMBER OF VALUES, FIRST POINT, INCREMENT
1 1.0	NUMBER OF SOURCES AND POWER DENSITY
1 40.0 20.0 40.0 20.0	WEIGHT, X, LENGTH ALONG X, Y, LENGTH ALONG Y

Table 2. Annotated output data file (output1.dat) for TXYZ20 program.

The data correspond to those contained in the file output1.dat which is generated for the case of a single heat source of unit weight. The first block of lines are the x,y,z, and calculated t(x,y,z) values. Beyond these are the listing of the input variables. In this and subsequent annotated output data file listings, it is important for the user to keep in mind the comments of p. 7 regarding the format used for the output data and the possible need for rounding.

×	y	Z	t(x,y,z)	
0.000000E+0	0 50.00000	0.000000E+00	107.2166	
10.00000	50.00000	0.000000E+00	229.7415	
20.00000	50.00000	0.000000E+00	899.0788	
30.00000	50.00000	0.000000E+00	3868.299	
40.00000	50.00000	0.000000E+00	17908.64	
50.00000	50.00000	0.000000E+00	29526.74	
60.00000	50.00000	0.000000E+00	17908.62	
70.00000	50.00000	0.000000E+00	3868.297	
80.00000	50.00000	0.000000E+00	899.0831	
90.00000	50.00000	0.000000E+00	229.7416	
100.0000	50.00000	0.000000E+00	107.2136	
STEADY-STATE	THERMAL ANALYSIS	CALCULATION USIN	G EQS. (13)-(23)	OF KOKKAS

THERMAL CONDUCTIVITIES AND LAYER THICKNESSES

LX= 100.00 LY= 100.00

L1= 1.00000 L2= 5.00000 L3= 4.00000

K1= 0.00100000 K2= 0.00010000 K3= 0.00500000

UPPER SUMMATION LIMITS NUP= 500 MUP= 500

NUMBER OF HEAT SOURCES= 1
POWER DENSITY= 1.000000

COORDINATES, LENGTHS, AND WIDTHS OF HEAT SOURCES

HEAT SOURCE	WTSOUR	XSOUR	YS0UR	LXS0UR	LYSOUR
1	1.00000	40.00000	40.00000	20.00000	20.00000

expect to see in the execution of the code. This particular input data file was used for the TXYZ20 code on several machines [4]. These include: a VAX 11/785, a SUN, a SPARC 2 and a CRAY. All of these systems had sufficient memory to compile the code and run it for the upper limits of 500. Users of the code on PCs may have to experiment to see if the dimension statements and the upper limits are too large. This will be influenced by the amount of RAM as well as the presence of a coprocessor. The execution of the code for this problem shows a range of relative speeds from 1 to 55. The results of this benchmark example are presented in table 3.

The above example makes use of the IEDGE=1 option for data entry. This can also be accomplished by using the IEDGE=2 option. This alternative is contained in the file input1a.dat which is annotated in table 4. The output from running these data is the same as contained in output1.dat (illustrated in table 2).

Other Examples

Several other examples are provided in the corresponding input and output data files. These show the use of the code for cases of (1) nonuniformly spaced points, and (2) several heat elements with various weights.

These are contained in the input2.dat and input3.dat files with the corresponding output data files of output2.dat and output3.dat. The example of input2.dat and output2.dat is annotated in tables 5 and 6.

This is for the case of a thick middle layer in the structure which can be handled with TXYZ20. The example of input3.dat and output3.dat is illustrated in tables 7 and 8. The specific example shows how to construct the problem for the case of two elements where one is a heat source and the other is a heat sink. Nonequispaced sets of x and z values are also used in the calculation. These examples contain all of the features of the use of the TXYZ20 code.

All of the input and output data files are provided to give the user hands-on experience with the use of the code and to make sure that the code is properly working on the user's machine.

Values of the thermal conductivity of materials of interest to the semiconductor community may be found in reference [5]. The use of the basic TXYZ code for thermal characterization is discussed there.

The code has also been used in the original TXYZ form for the modeling of MMIC devices (GaAs) for the determination of the channel temperature when the devices are undergoing life testing [6].

Finally, the field of thermal resistance measurements has been reviewed [7]. This reference contains results which are related to the use of the original TXYZ code.

Table 3. CPU times used in TXYZ20 calculation using input1.dat data.

This table presents the CPU time needed to carry out the calculation using the data in input1.dat (annotated in table 1) on several machines. This information is intended to provide a benchmark for the running of the TXZY2O code. The machines represented were used due to availability and do not represent a recommendation. The relative speeds presented cover a good deal of the spectrum to be expected.

Machine	CPU	Relative speed
VAX	457 sec.	1
SUN	205 sec.	2.2
SPARC 2	60 sec.	7.6
CRAY	8.375 sec.	55

Table 4. Annotated input data file (inputla.dat) for TXYZ20 code.

The data correspond to those contained in the file input1a.dat which can be used to run the case of a single heat source of unit weight. This illustrates the use of the IEDGEX = 2 generation of a set of values of x to be used in the calculation. The final set of data is equivalent to that of input1.dat for IEDGE = 1. The output is the same as that contained in output1.dat (discussed in table 2).

INPUT DATA	DESCRIPTION OF INPUT DATA
100 100 1 .001 5 .0001 4 .005 500 500 2	X AND Y DIMENSIONS OF RECTANGULAR STRUCTURE THICKNESS AND THERMAL CONDUCTIVITY OF TOP LAYER THICKNESS AND THERMAL CONDUCTIVITY OF MIDDLE LAYER THICKNESS AND THERMAL CONDUCTIVITY OF BOTTOM LAYER UPPER SUMMATION LIMITS FOR N AND M SUMMATIONS IEDGEX (=2, THEN READ IN INDIVIDUAL VALUES) NUMBER OF VALUES
0.0	X(1) FIRST VALUE OF X
10.	X(2) SECOND VALUE OF X
20.	X(3) .
30.	X(4)
40.	X(5) .
50.	X(6) .
60.	
70.	X(7) . X(8) .
80.	X(9) .
90.	X(10) .
100.	X(11) ELEVENTH VALUE OF X
100.	IEDGEY (=1, THEN READ IN THREE VALUES ON NEXT LINE)
1 50 0.0	NUMBER OF VALUES, FIRST POINT, INCREMENT
1 50. 0.0	IEDGEZ (=1, THEN READ IN THREE VALUES ON NEXT LINE)
1	NUMBER OF VALUES, FIRST POINT, INCREMENT
1 0.0 0.0	NUMBER OF VALUES, FIRST FUTIVE, INCREMENT
1 1.0	NUMBER OF SOURCES AND POWER DENSITY
1 40.0 20.0 40.0 20.0	WEIGHT, X, LENGTH ALONG X, Y, LENGTH ALONG Y

Table 5. Annotated input data file (input2.dat) for TXYZ20 code.

The data correspond to those contained in the file input2.dat which is used to illustrate the use of the IEDGEZ = 2 generation of a set of values of z to be used in the calculation. This is for the case of a thick middle layer where the original TXYZ code had difficulty with an artificial overflow. The output for this case is contained in output2.dat and is discussed in table 6.

INPUT DATA

DESCRIPTION OF INPUT DATA

1 IEDGEX (=1, THEN READ IN THREE VALUES ON NEXT LINE) 1 O. O. NUMBER OF VALUES, FIRST POINT, INCREMENT
1 IEDGEY (=1, THEN READ IN THREE VALUES ON NEXT LINE)
1 O. O. NUMBER OF VALUES, FIRST POINT, INCREMENT
2 IEDGEZ (=2, THEN READ IN INDIVIDUAL VALUES)
10 NUMBER OF VALUES
O. Z(1) FIRST VALUE OF Z
1.0 Z(2) SECOND VALUE OF Z
2.0 Z(3) .
Z(4) .
4.0 Z(5) .
4.5 Z(6) .
100. Z(7) .
200. Z(8) .
Z(9) .
240. Z(10) TENTH VALUE OF Z
1 1.0 NUMBER OF SOURCES AND POWER DENSITY
1 O. 53. O. 14. WEIGHT, X, LENGTH ALONG X, Y, LENGTH ALONG Y

Table 6. Annotated output data file (output2.dat) for TXYZ20 program.

The data correspond to those contained in the file output2.dat which is generated from the input data contained in input2.dat (see table 5). The first block of lines are the x,y,z, and calculated t(x,y,z) values. Beyond these are the listing of the input variables.

```
t(x,y,z)
                                  Z
0.000000E+00 0.000000E+00 0.000000E+00
                                             233445.2
0.0000000E+00 0.0000000E+00 -1.000000
                                             224832.5
0.0000000E+00 0.0000000E+00 -2.000000
                                             216600.1
0.000000E+00 0.000000E+00 -3.000000
                                             208748.5
0.000000E+00 0.000000E+00 -4.000000
                                             201273.0
0.0000000E+00 0.0000000E+00 -4.500000
                                             197674.8
0.0000000E+00 0.0000000E+00 -100.0000
                                             29815.45
0.0000000E+00 0.0000000E+00 -200.0000
                                             7110.651
0.0000000E+00 0.0000000E+00 -230.0000
                                             2989.828
0.000000E+00 0.000000E+00 -240.0000
                                             1686.604
STEADY-STATE THERMAL ANALYSIS CALCULATION USING EQS. (13)-(23) OF KOKKAS
```

UPPER SUMMATION LIMITS NUP= 50 MUP= 50

NUMBER OF HEAT SOURCES= 1 POWER DENSITY= 1.000000

COORDINATES, LENGTHS, AND WIDTHS OF HEAT SOURCES

HEAT SOURCE	WTSOUR	XSOUR	YS0UR	LXSOUR	LYSOUR
1	1.00000	0.00000	0.00000	53.00000	14.00000

Table 7. Annotated input data file (input3.dat) for TXYZ20 code.

The data correspond to those contained in the file input3.dat which is used to illustrate the use of the IEDGEX = 2 and IEDGEZ = 2 generation of a set of values of x and z to be used in the calculation. In addition, two elements are used. One is a source with a weight of 1.0 and the other is a sink with a weight of -1.0. The output for this case is contained in output2.dat and is discussed in table 8.

INPUT DATA	DESCRIPTION OF INPUT DATA
100 100 1 .001 5 .0001 4 .005 500 500 2	X AND Y DIMENSIONS OF RECTANGULAR STRUCTURE THICKNESS AND THERMAL CONDUCTIVITY OF TOP LAYER THICKNESS AND THERMAL CONDUCTIVITY OF MIDDLE LAYER THICKNESS AND THERMAL CONDUCTIVITY OF BOTTOM LAYER UPPER SUMMATION LIMITS FOR N AND M SUMMATIONS IEDGEX (=2, THEN READ IN INDIVIDUAL VALUES) NUMBER OF VALUES
40.	X(1) FIRST VALUE OF X
45. 46.	X(2) SECOND VALUE OF X
47.	X(3) . X(4) .
48.	X(5) .
52.	X(6) .
53.	X(7) .
54.	X(8) .
55.	X(9) .
60.	X(10) TENTH VALUE OF X
1	IEDGEY (=1, THEN READ IN THREE VALUES ON NEXT LINE)
1 50. 0.0	NUMBER OF VALUES, FIRST POINT, INCREMENT
2	IEDGEZ (=2, THEN READ IN INDIVIDUAL VALUES) NUMBER OF VALUES
9	Z(1) FIRST VALUE OF Z
1.0	Z(2) SECOND VALUE OF Z
2.0	Z(3) .
3.0	Z(4) .
4.0	Z(5) .
5.0	Z(6) .
6.0	2(7) .
9.0	Z(8) .
10.0	Z(9) NINTH VALUE OF Z
2 1.0	NUMBER OF SOURCES AND POWER DENSITY
-1. 55.0 10.0 45.0 10.0 -1. 55.0 10.0 45.0 10.0	WEIGHT, X, LENGTH ALONG X, Y, LENGTH ALONG Y WEIGHT, X, LENGTH ALONG X, Y, LENGTH ALONG Y

Table 8. Annotated output data file (output3.dat) for TXYZ20 program.

The data correspond to those contained in the file output3.dat which is generated from the input data contained in input3.dat (see table 7). The first block of lines are the x,y,z, and calculated t(x,y,z) values. Beyond these are the listing of the input variables. This example has been constructed to show not only variable x and z but also the use of negative weights on the elements in the construction of heat sinks. In this particular case, the two elements are of equal size are are symmetrically placed with respect to the middle of the structure. The calculated t(x,y,z) values directly reflect the opposite but equal weights of the two elements.

	.,	-	t(x,y,z)
x 40.00000	y 50.00000	z 0.000000E+00	13895.94
45.00000	50.00000	0.000000E+00	8401.479
46.00000	50.00000	0.0000000E+00	6187.981
47.00000	50.00000	0.0000000E+00	4418.474
48.00000	50.00000	0.0000000E+00	2844.606
52.00000	50.00000	0.0000000E+00	-2844.609
53.00000	50.00000	0.0000000E+00	-4418.476
54.00000	50.00000	0.0000000E+00	-6187.989
55.00000	50.00000	0.0000000E+00	-8401.491
60.00000	50.00000	0.000000E+00	-13895.94
40.00000	50.00000	-1.000000	13214.03
45.00000	50.00000	-1.000000	8048.078
46.00000	50.00000	-1.000000	6112.896
47.00000	50.00000	-1.000000	4373.840
48.00000	50.00000	-1.000000	2817.945
52.00000	50.00000	-1.000000	-2817.947
53.00000	50.00000	-1.000000	-4373.844
54.00000	50.00000	-1.000000	-6112.901
55.00000	50.00000	-1.000000	-8048.083
60.00000	50.00000	-1.000000	-13214.03
40.00000	50.00000	-2.000000	9877.484
45.00000	50.00000	-2.000000	6111.877
46.00000	50.00000	-2.000000	4777.800
47.00000	50.00000	-2.000000	3481.801
48.00000	50.00000	-2.000000	2265.086
52.00000	50.00000	-2.00000	-2265.088
53.00000	50.00000	-2.000000	-3481.803
54.00000	50.00000	-2.00000	-4777.805
55.00000	50.00000	-2.000000	-6111.882
60.00000	50.00000	-2.000000	-9877.482
40.00000	50.00000	-3.000000	7033.427
45.00000	50.00000	-3.000000	4407.094
46.00000	50.00000	-3.000000	3498.253
47.00000	50.00000	-3.000000	2583.641 1695.754
48.00000	50.00000	-3.000000	-1695.75 4
52.00000	50.00000	-3.00000 -3.00000	-2583.643
53.00000	50.00000	-3.000000	-3498.257
54.00000	50.00000 50.00000	-3.000000	-4407.097
55.00000 60.00000	50.00000	-3.000000	-7033.424
00.00000	50.00000	-3.00000	7000.724

X	у ,	Z	t(x,y,z)
40.00000	50.00000	-4.000000	4544.860
45.00000	50.00000	-4.000000	2873.673
46.00000	50.00000	-4.000000	2300.854
47.00000	50.00000	-4.000000	1713.657
48.00000	50.00000	-4.000000	1131.903
52.00000	50.00000	-4.000000	-1131.905
53.00000	50.00000	-4.000000	-1713.658
54.00000	50.00000	-4.000000	-2300.855
55.00000	50.00000	-4.000000	-2873.675
60.00000	50.00000	-4.000000	-4544.859
40.00000	50.00000	-5.000000	2285.325
45.00000	50.00000	-5.000000	1453.400
46.00000	50.00000	-5.000000	1169.267
47.00000	50.00000	-5.000000	875.0942
48.00000	50.00000	-5.000000	580.2814
52.00000	50.00000	-5.000000	-580.2822
53.00000	50.00000	-5.000000	-875.0949
54.00000	50.00000	-5.000000	-1169.268
55.00000	50.00000	-5.000000	-1453.401
60.00000	50.00000	-5.000000	-2285.325
40.00000	50.00000	-6.000000	139.8420
45.00000	50.00000	-6.000000	90.59629
46.00000	50.00000	-6.000000	73.84338
47.00000	50.00000	-6.000000	56.01737
48.00000	50.00000	-6.000000	37.57924
52.00000	50.00000	-6.000000	-37.57928
53.00000	50.00000	-6.000000	-56.01740
54.00000	50.00000	-6.000000	-73.84344
55.00000	50.00000	-6.000000	-90.59635
60.00000	50.00000	-6.000000	-139.8419
40.00000	50.00000	-9.000000	31.62482
45.00000	50.00000	-9.000000	20.66124
46.00000	50.00000	-9.000000	16.93877
47.00000	50.00000	-9.000000	12.92600
48.00000	50.00000	-9.000000	8.715524
52.00000	50.00000	-9.000000	-8.715535
53.00000	50.00000	-9.000000	-12.92601
54.00000	50.00000	-9.000000	-16.93879
55.00000	50.00000	-9.000000	-20.66125
60.00000	50.00000	-9.000000	-31.62481
40.00000	50.00000	-10.00000	0.000000E+00
45.00000	50.00000	-10.00000	0.000000E+00
46.00000	50.00000	-10.00000	0.000000E+00
47.00000	50.00000	-10.00000	0.000000E+00
48.00000	50.00000	-10.00000	0.000000E+00
52.00000	50.00000	-10.00000	0.000000E+00
53.00000	50.00000	-10.00000	0.000000E+00
54.00000	50.00000	-10.00000	0.000000E+00
55.00000	50.00000	-10.00000	0.000000E+00
60.00000	50.00000	-10.00000	0.000000E+00

STEADY-STATE THERMAL ANALYSIS CALCULATION USING EQS. (13)-(23) OF KOKKAS

UPPER SUMMATION LIMITS NUP= 500 MUP= 500

NUMBER OF HEAT SOURCES= 2 POWER DENSITY= 1.000000

COORDINATES, LENGTHS, AND WIDTHS OF HEAT SOURCES

HEAT SOUR	CE WTSOUR	XSOUR	YSOUR	LXSOUR	LYSOUR
1	1.00000	35.00000	45.00000	10.00000	10.00000
2	-1.00000	55.00000	45.00000	10.00000	10.00000

Acknowledgments

The author would like to thank Harry Schafft for his continued use of the code and the collaboration on the electromigration problem which fostered the variable weight idea and the use of the code for sinks as well as sources.

The author would also like to thank Dave Blackburn for using the code for two-dimensional temperature contour generation and for using thick middle layers which gave interesting results.

Finally, the author thanks all of the TXYZ users for making use of the code. He hopes that TXYZ users become TXYZ20 users.

References

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- [3] Schafft, H. A., and Albers, J., Thermal Interactions Between Electromigration Test Structures, *IEEE Proceedings on Microelectronic Test Structures*, Vol. 1, No. 1, pp. 132-137 (February 1988).
- [4] Certain commercial equipment, instruments, or materials are identified in this paper in order to specify the procedure adequately. Such identification does not imply recommendation or endorsement by the National Institute of Standards and Technology, nor does it imply that the materials or equipment identified are necessarily the best available for the purpose. In spite of the author's experience that the program performs correctly with every set of data which has been tried, there can be no assurance that the program will perform equally well on all (possibly anomalous) data. Therefore, both the author and NIST assume no liability for any possible losses resulting from the use of this program.
- [5] Oettinger, F. F., Thermal Evaluation of VLSI Packages Using Test Chips A Critical Review, Solid State Technology (February 1984).
- [6] Wright, J. L., Marks, B. W., and Decker, K. D., Modeling of MMIC Devices for Determining MMIC Channel Temperatures During Life Tests, Proceedings of the Seventh IEEE SEMI-THERM Symposium, pp. 131-139 (1991).
- [7] Oettinger, F. F., and Blackburn, D. L., Semiconductor Measurement Technology: Thermal Resistance Measurements, NIST Special Publication 400-86 (July 1990).

APPENDIX

TXYZ VERSION 2.0

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C

THIS PROGRAM CALCULATES THE STEADY-STATE TEMPERATURE DISTRIBUTION, T(X,Y,Z), DUE TO DC POWER INPUTS/OUTPUTS. THE TEMPERATURE IS RÈLATIVE TO THE AMBIENT. THE SPECIFIC EQUATIONS USED ARE GIVEN IN EQUATIONS (13)-(23), WITH S=0 (ZERO FREQUENCY, STEADY-STATE CONDITION). IN THE PAPER BY KOKKAS.

REFERENCES: THE ORIGINAL MATHEMATICAL ANALYSIS OF THE THREE LAYER STRUCTURE WAS PERFORMED IN THE PAPER "THERMAL ANALYSIS OF MULTIPLE-LAYERED STRUCTURES" BY ACHILLES G. KOKKAS, IEEE TRANS. ELEC. DEV. VOL. ED-21, NO. 11, 674-681 (1974)). THE ORIGINAL FORTRAN IMPLEMENTATION OF THE STEADY STATE IN THE FORM OF THE ORIGINAL TXYZ CODE IS PRESENTED IN THE REPORT "SEMICONDUCTOR MEASUREMENT TECHNOLOGY: TXYZ: A PROGRAM FOR SEMICONDUCTOR IC THERMAL ANALYSIS" BY JOHN

ALBERS, NBS SPEC. PUBL. 400-76 (APRIL 1984)

THE CALCULATION IS PERFORMED FOR A RECTANGULAR THREE LAYER STRUCTURE WITH AN ARBITRARY NUMBER OF RECTANGULAR HEAT SOURCES/SINKS ON THE TOP SURFACE. THE TEMPERATURE MAY BE CALCULATED AT ANY POINT (X,Y,Z) INSIDE OR ON THE SURFACES OF THE STRUCTURE. THE CALCULATION FOLLOWS FROM THE INPUT OF THE THICKNESSES AND THERMAL CONDUCTIVITIES OF THE THREE LAYERS. IT IS IMPORTANT TO EMPHASIZE THAT THE CALCULATION IS GENERAL FOR THE THREE LAYER STRUCTURE AND THE APPLICATION TO SEMICONDUCTOR STRUCTURES IS A SPECIAL CASE.

```
DIMENSION X(100), Y(100), Z(100), COSYT(500)
     DIMENSION ARUZER(500,500), ARFUNZ(500,500)
     DIMENSION WTSOUR(50), XSOUR(50), YSOUR(50), REAL LXSOUR(50), LYSOUR(50), K1, K2, K3, LX, LY, L1, L2, L3
     COMMON K1, K2, K3, LX, LY, L1, L2, L3
     COMMON NSOUR, WTSOUR, XSOUR, YSOUR, LXSOUR, LYSOUR
     PI=3.14159265
1
     FORMAT (1H1)
    FORMAT(1X, 'STEADY-STATE THERMAL ANALYSIS CALCULATION USING EQS. 1 (13)-(23) OF KOKKAS'/)
3
     FORMAT(1X, 'THERMAL CONDUCTIVITIES AND LAYER THICKNESSES')
     FORMAT(1X, 'K1= ',F10.8,' K2= ',F10.8,' K3= ',F10.8)
FORMAT(1X, 'L1= ',F10.5,' L2= ',F10.5,' L3= ',F10.5)
5
     FORMAT(/1X, 'UPPER SUMMATION LIMITS ',2X,' NUP=', I5,
    1 ' MUP=', I5/)
     FORMAT(//1X, 'NUMBER OF HEAT SOURCES=', I5)
7
     FORMAT(/1X,'COORDINATES, LENGTHS, AND WIDTHS OF HEAT SOURCES'/)
     FORMAT (1X, 'HEAT SOURCE ', 3X, 'WTSOUR', 5X, 'XSOUR', 9X, 'YSOUR', 8X,
    1 'LXSOUR',8X,'LYSOUR'/)
     FORMAT (4X, I3, 5X, F10.5, 3X, F10.5, 3X, F10.5, 3X, F10.5, 3X, F10.5)
     FORMAT(1X, 'POWER DENSITY=',F11.6)
11
     FORMAT (/1X, 'CALCULATING', 13,' X POINTS WITH A FIRST POINT OF'
12
    1 ,F11.6, 'AND A STEP SIZE OF ',F11.6)
     FORMAT(/1X, 'THE CONSTANT X COORDINATE IS ',F11.6)
13
     FORMAT (/1X, 'CALCULATING ', 13, ' Y POINTS WITH A FIRST POINT OF '
14
        ,F11.6, 'AND A STEP SIZE OF ',F11.6)
     FORMAT (/1X, 'THE CONSTANT Y COORDINATE IS ',F11.6)
15
     FORMAT(/1X, 'CALCULATING ', I3, ' Z POINTS WITH A FIRST POINT OF '
16
        ,F11.6, 'AND A STEP SIZE OF ',F11.6)
17
     FORMAT (/1X, 'THE CONSTANT Z COORDINATE IS ',F11.6)
     FORMAT(1X, 'LX=', F7.2, 3X, 'LY=', F7.2)
27
     FORMAT (1X, F12.4, 2X, F12.4, 2X, F12.4, 2X, F12.4)
22
     FORMAT(1X,6I7)
31
     FORMAT(1X, I4, 3X, I4)
51
52
     FORMAT (1X, F10.5, 3X, F10.5)
     FORMAT(1X, I1)
53
     FORMAT(1X, I4, 3X, F10.5, 3X, F10.5)
54
55
     FORMAT (1X, F10.5)
     FORMAT(1X, I2, 3X, F10.5)
56
     FORMAT (1X, F10.5, 3X, F10.5, 3X, F10.5, 3X, F10.5)
57
    FORMAT(1X, 'YOUR UPPER LIMIT OF SUMMATION IS TOO LARGE. TRY AGAIN')
```

```
C
C
                     ----INPUT SECTION----
C
      THE FOLLOWING VARIABLES ARE READ BY THE PROGRAM FROM FORO10
C
C
          LX----X DIMENSION OF 3 LAYER STRUCTURE
C
          LY----Y DIMENSION OF 3 LAYER STRUCTURE
C
          L1----THICKNESS OF TOP LAYER
C
          K1----THERMAL CONDUCTIVITY OF TOP LAYER
C
          L2----THICKNESS OF MIDDLE LAYER
C
          K2----THERMAL CONDUCTIVITY OF MIDDLE LAYER
          L3----THICKNESS OF BOTTOM LAYER
C
          K3----THERMAL CONDUCTIVITY OF BOTTOM LAYER
C
          NUP-----UPPER LIMIT OF N SUM, X DIRECTION
C
          MUP-----UPPER LIMIT OF M SUM. Y DIRECTION
C
00000
          IEDGEX----INDEX FOR GENERATING THE VALUES OF X TO BE USED
                     =1 TO READ DATA FOR FIXED INCREMENT X VALUES
                     =2 TO READ IN ARRAY OF X VALUES OF NONFIXED INCREMENT)
                    IF IEDGEX=1 THEN READ THE THREE VARIABLES (ON SAME LINE)
                        ILX THE NUMBER OF X VALUES TO BE USED
C
                        X1
                             THE VALUE OF THE FIRST POINT IN X
C C C
                        STEPX (THE INCREMENT IN X)
                    IF IEDGEX=2 THEN READ THE VARIABLE AND ARRAY (ONE PER LINE)
                        ILX THE NUMBER OF X VALUES TO BE USED
C
                        X(I) THE ARRAY OF X VALUES (I=1,ILX)
C
          IEDGEY----INDEX FOR GENERATING THE VALUES OF Y TO BE USED
00000
                     =1 TO READ DATA FOR FIXED INCREMENT Y VALUES
                     =2 TO READ IN ARRAY OF X VALUES OF NONFIXED INCREMENT)
                    IF IEDGEY=1 THEN READ THE THREE VARIABLES (ON SAME LINE)
                        ILY THE NUMBER OF Y VALUES TO BE USED
                             THE VALUE OF THE FIRST POINT IN Y
C
                        STEPY (THE INCREMENT IN Y)
00000
                    IF IEDGEY=2 THEN READ THE VARIABLE AND ARRAY (ONE PER LINE)
                        ILY THE NUMBER OF Y VALUES TO BE USED
                        Y(I) THE ARRAY OF Y VALUES (I=1,ILY)
          IEDGEZ----INDEX FOR GENERATING THE VALUES OF Z TO BE USED
C
                     =1 TO READ DATA FOR FIXED INCREMENT Z VALUES
00000
                     =2 TO READ IN ARRAY OF Z VALUES OF NONFIXED INCREMENT)
                    IF IEDGEZ=1 THEN READ THE THREE VARIABLES (ON SAME LINE)
                        ILZ THE NUMBER OF Z VALUES TO BE USED
                             THE VALUE OF THE FIRST POINT IN Z
                        STEPZ (THE INCREMENT IN Z)
C
                    IF IEDGEZ=2 THEN READ THE VARIABLE AND ARRAY (ONE PER LINE)
00000
                        ILZ THE NUMBER OF Z VALUES TO BE USED
                        Z(I) THE ARRAY OF Z VALUES (I=1, ILZ)
         NOTE: ENTER THE Z-RELATED VARIABLES (Z1, STEPZ OR THE Z(I) ARRAY)
               AS ZERO OR POSITIVE QUANTITIES. THE PROGRAM CONVERTS THE FINAL
               Z(I) ARRAY TO ZERO OR NEGATIVE QUANTITIES AS THE CALCULATION
Ċ
C
               TAKES THE Z VARIABLE TO BE ZERO OR NEGATIVE.
C
```

```
C
          NSOUR----NUMBER OF HEAT SOURCES (UP TO 50)
          PO----POWER DENSITY
C
C
C
          THE NEXT NSOUR LINES READ THE FOLLOWING INFORMATION FOR THE
C
C
          HEAT SOURCES (WITH ALL THE INFORMATION FOR EACH OF THE ELEMENTS
                       ON A SINGLE LINE)
C
00000
          WTSOUR(I)-WEIGHTING FACTOR OF I-TH SOURCE
                    (POSITIVE FOR SOURCE, NEGATIVE FOR SINK)
          XSOUR(I) -- X COORDINATE OF ORIGIN OF I-TH SOURCE
          LXSOUR(I)-LENGTH ALONG X DIRECTION OF I-TH SOURCE
          YSOUR(I)--Y COORDINATE OF ORIGIN OF I-TH SOURCE
C
          LYSOUR(I)-LENGTH ALONG Y DIRECTION OF I-TH SOURCE
C**
   **********************
C
     READ LX AND LY (THE X AND Y DIMENSIONS OF THE RECTANGULAR STRUCTURE)
     READ(10,*) LX, LY
C
     READ L1 AND K1 (THICKNESS AND THERMAL CONDUCTIVITY OF THE TOP LAYER)
      READ(10,*) L1, K1
C
      READ L2 AND K2 (THICKNESS AND THERMAL CONDUCTIVITY OF THE MIDDLE LAYER)
      READ(10,*) L2, K2
C
      READ L3 AND K3 (THICKNESS AND THERMAL CONDUCTIVITY OF THE BOTTOM LAYER)
     READ(10,*) L3, K3
C
     READ NUP AND MUP (UPPER LIMIT OF THE SUMMATION OVER THE INDEX N (X-DIR)
C
                       UPPER LIMIT OF THE SUMMATION OVER THE INDEX M (Y-DIR))
      READ(10,*)NUP, MUP
C
      NUP AND MUP MUST BE LESS THAN OR EQUAL TO THE DIMENSIONALITY OF
      IF (NUP.GT.500.OR.MUP.GT.500) GO TO 3999
     READ(10,*)IEDGEX
     GOTO (110,115) IEDGEX
     READ (10,*)ILX,X1,STEPX
110
      DO 111 I=1, ILX
     X(I)=X1+(I-1)*STEPX
111
     CONTINUE
      GOTO 119
     READ (10,*)ILX
115
     DO 116 I=1,ILX
     READ(10,*)X(I)
116
     CONTINUE
119
     READ(10,*)IEDGEY
      GOTO (120,125) IEDGEY
     READ (10,*)ILY,Y1,STEPY
120
      DO 121 I=1, ILY
      Y(I)=Y1+(I-1)*STEPY
     CONTINUE
 121
      GOTO 129
     READ (10,*) ILY
125
     DO 126 I=1, ILY
     READ(10,*)Y(I)
 126 CONTINUE
```

```
129
     READ(10,*)IEDGEZ
     GOTO (130,135) IEDGEZ
     READ (10,*)ILZ,Z1,STEPZ
 130
     Z1 = -1.0 * Z1
     STEPZ=-1.0*STEPZ
     DO 131 I=1, ILZ
     Z(I)=Z1+(I-1)*STEPZ
131
     CONTINUE
     GOTO 139
135
     READ (10,*)ILZ
     DO 136 I=1.ILZ
     READ(10,*)Z(I)
     Z(I) = -1.0*Z(I)
136
     CONTINUE
     READ THE NUMBER OF HEAT SOURCES AND THE POWER DENSITY
C
     NOTE-POWER DENSITY IS MULTIPLICATIVE FACTOR USUALLY SET EQUAL TO UNITY
139
     READ(10, *) NSOUR, PO
     PO IS THE POWER DENSITY, ASSUMED UNIFORM FOR ALL HEATERS
C
     NSOUR IS THE TOTAL NUMBER OF HEATING ELEMENTS ON THE SURFACE OF THE
C
     THE TOP LAYER (UP TO 50)
C
     THE NEXT LOOP READS IN THE COORDINATES OF THE ORIGIN OF THE
C
     HEATING ELEMENTS ALONG WITH THEIR LENGTHS AND WIDTHS
     THE WEIGHTING FACTOR IS ALSO ENTERED (THIS IS REAL, NONINTEGER)
     D0 100 I=1, NSOUR
     READ(10,*)WTSOUR(I), XSOUR(I), LXSOUR(I), YSOUR(I), LYSOUR(I)
C
     WTSOUR(I) IS THE WEIGHTING FACTOR FOR THE I-TH HEATER ELEMENT
C
     XSOUR(I) IS THE X COORDINATE OF THE ORIGIN OF I-TH HEATER ELEMENT
C
     LXSOUR(I) IS THE LENGTH OF THE I-TH HEATER ALONG THE X DIRECTION
     YSOUR(I) IS THE Y COORDINATE OF THE ORIGIN OF I-TH HEATER ELEMENT
     LYSOUR(I) IS THE LENGTH OF THE I-TH HEATER ALONG THE Y DIRECTION
100
     CONTINUE
     PO4LK = 4.0 * PO / (LX* LY* K1)
     PILX = PI / LX
     PILY = PI / LY
C
C
     END OF DATA INPUT SECTION
C
     BEGIN CALCULATION OF T(X,Y,Z)
     THE SUBROUTINES USED IN THE CALCULATION ARE:
C
     1) UZERO(N,M) - CALCULATES THE FOURIER COSINE TRANSFORM OF THE
C
C
        FUNCTION, U(X,Y), THE POWER DENSITY FUNCTION FOR ALL OF THE
C
        HEAT SOURCES.
     2) FUNZ(N,M,Z) - CALCULATES THE Z-DEPENDENT PORTION OF THE SUM
C
        REMEMBERING THAT THIS IS A FUNCTION OF THE SUMMATION
        INDICES (N,M).
     CALCULATE THE FOURIER COMPONENTS OF THE HEAT SOURCES, U(N,M)
DO 300 MM=1, MUP
     M = MM - 1
     DO 250 NN=1, NUP
        N = NN - 1
        ARUZER (NN, MM) = UZERO (N, M)
250 CONTINUE
300 CONTINUE
```

```
C
C
     END OF U(N,M) CALCULATION AND BEGINNING OF MAJOR LOOP FOR Z
C
DO 3000 IZ=1,ILZ
CALCULATE THE Z DEPENDENT POTION, I.E., FUNZ(N,M,Z)
DO 400 MM=1,MUP
    M = MM - 1
    DO 350 NN=1, NUP
       N = NN - 1
       ARFUNZ(NN,MM) = FUNZ(N,M,Z(IZ)) *ARUZER(NN,MM)
350
    CONTINUE
    CONTINUE
400
    DO 3000 IY=1, ILY
    DO 700 MM=1, MUP
       M = MM - 1
       COSYT(MM)=COS(FLOAT(M)*Y(IY)*PILY)
700
    CONTINUE
    DO 3000 IX=1, ILX
       SUM=0.0
       DO 1900 MM=1, MUP
       M = MM - 1
       DO 1700 NN=1, NUP
         N = NN - 1
         NDN=0
         NDM=0
         IF (N.EQ.O) NDN=1
         IF (M.EQ.O) NDM=1
         TOP = ARFUNZ(NN,MM) * COS(FLOAT(N)*X(IX)*PILX) * COSYT(MM)
         BOTTOM = (NDN+1) * (NDM+1)
         TSUM=TOP/BOTTOM
          SUM=SUM+TSUM
       CONTINUE
1700
       CONTINUE
1900
       TEMP = PO4LK * SUM
       WRITE (12,*)X(IX),Y(IY),Z(IZ),TEMP
        WRITE (12,22)X(IX),Y(IY),Z(IZ),TEMP
3000 CONTINUE
     WRITE(12,1)
    WRITE(12,2)
     WRITE(12,3)
     WRITE(12,27) LX, LY
     WRITE(12,5) L1, L2, L3
     WRITE(12,4) K1, K2, K3
     WRITE(12,6)NUP,MUP
     WRITE (12,7) NSOUR
     WRITE(12,11) PO
     WRITE (12,8)
     WRITE(12,9)
     DO 3888 I=1,NSOUR
    WRITE(12,10)I, WTSOUR(I), XSOUR(I), YSOUR(I), LXSOUR(I), LYSOUR(I)
```

```
3888 CONTINUE
     GO TO 4000
3999 WRITE(6,88)
4000 STOP
     END
     END OF THE MAIN PROGRAM
C
C
     FUNCTION UZERO LISTING
C
     DESCRIPTION OF THE FUNCTION UZERO(N,M)
C
     THIS FUNCTION CALCULATES THE DOUBLE FOURIER COSINE TRANSFORM
C
     OF THE POWER DENSITY FUNCTION, U(X,Y). THIS IS THE TRANSFORM FOR ALL OF THE HEAT SOURCES. THE ASSUMPTION IS MADE THAT THE
C
C
     POWER DENSITY IS UNIFORM AND EQUAL TO UNITY OVER THE SURFACE
C
     OF THE HEATING ELEMENTS. THAT IS,
                 (XSOUR(I) \le X \le XSOUR(I) + LXSOUR(I) AND
C
       U(X,Y)=1
C
                  YSOUR(I) = Y = YXOUR(I) + LYSOUR(I).
Ċ
       U(X,Y)=0 OTHERWISE.
     UNDER THESE CONDITIONS, IT IS POSSIBLE TO ANALYTICALLY EVALUATE
C
C
     THE DOUBLE INTEGRAL FOR EACH HEATING ELEMENT. AS THE HEATING
C
     ELEMENTS ARE ASSUMED TO BE INDEPENDENT, THE CONTRIBUTION FROM
C
     EACH ELEMENT MAY BE ADDED TO OBTAIN THE U(N,M) FOR ALL.
C
C
     NONUNIFORM POWER DENSITIES MAY BE TAKEN CARE OF BY USING THE
     WEIGHTING FACTOR FOR EACH ELEMENT (READ IN THE MAIN PROGRAM)
FUNCTION UZERO (N, M)
     DIMENSION WTSOUR(50), XSOUR(50), YSOUR(50),
     REAL LXSOUR(50), LYSOUR(50), K1, K2, K3, LX, LY, L1, L2, L3
     COMMON K1, K2, K3, LX, LY, L1, L2, L3
     COMMON NSOUR, WTSOUR, XSOUR, YSOUR, LXSOUR, LYSOUR
     PI=3.14159265
     UZER0=0.0
     DO 500 I=1, NSOUR
        IF(N.EQ.O) GO TO 100
          TERMX = SIN(FLOAT(N)*PI*(XSOUR(I) + LXSOUR(I)) / LX)
                  - SIN(FLOAT(N)*PI*XSOUR(I)/LX)
          TERMX=TERMX* LX/(FLOAT(N)*PI)
          GO TO 150
        TERMX= LXSOUR(I)
 100
        IF(M.EQ.O) GO TO 200
 150
          TERMY = SIN(FLOAT(M)*PI*(YSOUR(I) + LYSOUR(I))/LY)
                  - SIN(FLOAT(M)*PI*YSOUR(I)/LY)
    1
          TERMY=TERMY* LY/(FLOAT(M)*PI)
          GO TO 250
        TERMY= LYSOUR(I)
200
250
        TERMI=TERMX*TERMY
        UZERO=UZERO+TERMI*WTSOUR(I)
     CONTINUE
 500
     RETURN
     END
```

```
C
      FUNCTION FUNZ LISTING
C
C
      DESCRIPTION OF THE FUNCTION FUNZ(N,M,Z)
      THIS FUNCTION IS USED TO CALCULATE THE Z DEPENDENT PART OF THE
C
C
      FUNCTION USING THE S=0 VERSIONS OF EQUATIONS (15)-(17) OF KOKKAS.
C
      THESE ARE USED IN CONJUNCTION WITH EQUATIONS (18)-(22) ALSO FOR
      S=O (STEADY-STATE CONDITION). THE SPECIFIC FORM OF FUNZ IS DETERMINED BY THE VALUE OF Z, I.E., IF Z FALLS IN THE TOP, MIDDLE
C
Ċ
C
      OR BOTTOM LAYER OF THE STRUCTURE. IN ADDITION, SPECIAL CARE IS
C
      TAKEN AS TO EVALUATE FUNZ FOR THE CASE WHERE GAMMA=O AS THESE ARE
C
      SIMPLE, BUT THE COMPUTER DOES NOT KNOW HOW TO EVALUATE LIMITS.
C
      IN ADDITION, THE FORM OF THE THREE SOLUTIONS HAS BEEN CHANGED TO
C
      GET RID OF THE ARTIFICIAL OVERFLOW PROBLEMS COMING FROM THE
C
      HYPERBOLIC FUNCTIONS, COSH AND SINH, FOR THE CASES WHERE THE
C
      ARGUMENTS BECOME LARGE.
  **********************
      FUNCTION FUNZ(N,M,Z)
     DIMENSION WTSOUR(50), XSOUR(50), YSOUR(50),
      REAL LXSOUR(50), LYSOUR(50), K1, K2, K3, LX, LY, L1, L2, L3
      COMMON K1, K2, K3, LX, LY, L1, L2, L3
      COMMON NSOUR, WTSOUR, XSOUR, YSOUR, LXSOUR, LYSOUR
      PI=3.14159265
      GAMMA=SQRT((FLOAT(N)*PI/LX)**2 + (FLOAT(M)*PI/LY)**2)
      VS=GAMMA* L1
      VC=GAMMA* L2
      VI=GAMMA* L3
      VT=GAMMA*(L1+Z)
      VM=GAMMA*(L1+L2+Z)
      VB=GAMMA*(L1+L2+L3+Z)
      BOT1=TANH(VS) *TANH(VI)
      B0T1=B0T1+(K3/K2)*TANH(VS)*TANH(VC)
      BOT2=(K2/K1)*TANH(VI)*TANH(VC)+(K3/K1)
      GFUNC=1.0/(B0T1+B0T2)
      AZ=ABS(Z)
      IF (AZ.GT. L1) GO TO 500
```

```
C
           TOP LAYER CALCULATION
C
     THIS PORTION IS THE TOP LAYER CALCULATION WHICH IS DEFAULTED
C
     TO IF Z FALLS INTO THE TOP LAYER
     IF (GAMMA.EQ.O.O) GO TO 100
     TERMS1=TANH(VI)+( K3/ K2)*TANH(VC)
     TERMS2=(K2/K1)*TANH(VT)*(TANH(VI)*TANH(VC)+(K3/K2))
     TERMS=TERMS1+TERMS2
     IF (Z.EQ.O.O) GO TO 90
     IF (VS.GT.5.0.AND.VT.GT.5.0) GO TO 80
     IF (VS.LT.5.0) GO TO 10
     C1=2.0*EXP(-VS)
     GO TO 20
     C1=1.0/COSH(VS)
10
20
     CONTINUE
     IF (VT.LT.5.0) GO TO 30
     C2=0.5*EXP(VT)
     GO TO 40
     C2=COSH(VT)
30
40
     CONTINUE
     FUNZ=GFUNC*TERMS*C1*C2/GAMMA
     RETURN
80
     FUNZ=GFUNC*TERMS*EXP(GAMMA*Z)/GAMMA
     RETURN
     FUNZ=GFUNC*TERMS/GAMMA
90
     RETURN
100
     FUNZ=(L1+Z)+(K1/K2)*L2+(K1/K3)*L3
     RETURN
500
     TOTAL= L1+ L2
     IF (AZ.GT.TOTAL) GO TO 1500
```

```
C
           MIDDLE LAYER CALCULATION
     THIS IS THE MIDDLE LAYER CALCULATION WHICH IS DEFAULTED TO IF
C
C
     Z FALLS INTO THIS DOMAIN OF DEPTHS
     IF (GAMMA.EQ.O.O) GO TO 1000
     TERMC=TANH(VI)+(K3/K2)*TANH(VM)
     IF (VS.GT.5.0.AND.VC.GT.5.0.AND.VM.GT.5.0) GO TO 800
     IF (VS.LT.5.0.AND.VC.GT.5.0.AND.VM.GT.5.0) GO TO 900
     IF (VS.LT.5.0) GO TO 250
     C1=2.0*EXP(-VS)
     GO TO 260
250
    C1=1.0/COSH(VS)
260 CONTINUE
     IF (VC.LT.5.0) GO TO 270
     C2=2.0*EXP(-VC)
     GO TO 280
    C2=1.0/COSH(VC)
270
280 CONTINUE
     IF (VM.LT.5.0) GO TO 320
     C3=0.5*EXP(VM)
     GO TO 330
320
    C3=COSH(VM)
330
    CONTINUE
     FUNZ=GFUNC*TERMC*C1*C2*C3/GAMMA
     RETURN
800 FUNZ=GFUNC*TERMC*2.0*EXP(GAMMA*Z)/GAMMA
     RETURN
900 FUNZ=GFUNC*TERMC*EXP(VS+GAMMA*Z)/(COSH(VS)*GAMMA)
     RETURN
1000 FUNZ=( K1/ K3)* L3+( K1/ K2)*( L1+ L2+Z)
     RETURN
```

```
BOTTOM LAYER CALCULATION
C
C
      THIS IS THE BOTTOM LAYER CALCULATION WHICH IS USED IF Z FALLS
C
      INTO THE BOTTOM LAYER
1500 IF (GAMMA.EQ.O.O) GO TO 2000
      IF (VS.GT.5.0.AND.VC.GT.5.0.AND.VI.GT.5.0.AND.
    1 VB.GT.5.0) GO TO 1900
      IF (VB.GT.5.0.AND.VS.GT.5.0.AND.VC.LT.5.0.AND.VI.LT.5.0)G0 TO 2100
      IF(VB.GT.5.0.AND.VS.LT.5.0.AND.VC.GT.5.0.AND.VI.LT.5.0)G0 T0 2200
      IF(VB.GT.5.0.AND.VS.LT.5.0.AND.VC.LT.5.0.AND.VI.GT.5.0)G0 TO 2300
      IF(VB.GT.5.0.AND.VS.GT.5.0.AND.VC.GT.5.0.AND.VI.LT.5.0)G0 TO 2400
      IF(VB.GT.5.0.AND.VS.GT.5.0.AND.VC.LT.5.0.AND.VI.GT.5.0)G0 TO 2500
      IF(VB.GT.5.0.AND.VS.LT.5.0.AND.VC.GT.5.0.AND.VI.GT.5.0)G0 TO 2600
      IF (VS.LT.5.0) GO TO 1550
      C1=2.0*EXP(-VS)
      GO TO 1560
1550 C1=1.0/C0SH(VS)
1560 CONTINUE
      IF (VC.LT.5.0) GO TO 1570
      C2=2.0*EXP(-VC)
      GO TO 1580
1570 C2=1.0/C0SH(VC)
1580 CONTINUE
      IF (VI.LT.5.0) GO TO 1590
      C3=2.0*EXP(-VI)
      GO TO 1600
1590 C3=1.0/COSH(VI)
1600 CONTINUE
      C4=SINH(VB)
      FUNZ=GFUNC*C1*C2*C3*C4/GAMMA
     RETURN
1900 FUNZ=GFUNC*4.0*EXP(GAMMA*Z)/GAMMA
     RETURN
2000 FUNZ=( K1/ K3)*( L1+ L2+ L3+Z)
      RETURN
2100 FUNZ=GFUNC*EXP(VB-VS)/(GAMMA*COSH(VC)*COSH(VI))
     RETURN
2200 FUNZ=GFUNC*EXP(VB-VC)/(GAMMA*COSH(VS)*COSH(VI))
     RETURN
2300 FUNZ=GFUNC*EXP(VB-VI)/(GAMMA*COSH(VS)*COSH(VC))
      RETURN
2400 FUNZ=GFUNC*2.0*EXP(VB-VS-VC)/(GAMMA*COSH(VI))
     RETURN
2500 FUNZ=GFUNC*2.0*EXP(VB-VS-VI)/(GAMMA*COSH(VC))
      RETURN
2600 FUNZ=GFUNC*2.0*EXP(VB-VC-VI)/(GAMMA*COSH(VS))
      RETURN
      END
```



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10. SUPPLEMENTARY NOTES

11. ABSTRACT (A 200-WORD OR LESS FACTUAL SUMMARY OF MOST SIGNIFICANT INFORMATION. IF DOCUMENT INCLUDES A SIGNIFICANT BIBLIOGRAPHY OR LITERATURE SURVEY, MENTION IT HERE.) The TXYZ computer program has been used for a number of years for the thermal analysis of semiconductor devices and packages. This program makes use of the closed form, Fourier series solution of the steady-state heat flow equation for the general case of a rectangular three-layer structure with multiple heat sources on the top surface. TXYZ provides for the calculation of the temperature at any set of points in this structure and has proven useful for the determination of the steady-state temperature distribution of semiconductor chips and packages. This report presents TXYZ20 (TXYZ Version 2.0) which is a revised and updated version of the original TXYZ program. The TXYZ20 program incorporates more flexible handling of input data, assignment of positive or negative noninteger weights to the various heat sources or heat sinks, and improved evaluation of limiting forms in the code. The first part of this report consists of a discussion of the general elements in the TXYZ code and the particular changes which have been made to it to obtain TXYZ20. The second part of the report contains a discussion of several examples of the running of the code. Several annotated input data files are presented and discussed to show both the increased flexibility of the input data and the actual use of the updated code. Running the TXYZ20 code for one of the input files provides a benchmark for several machines. The user may wish to run this example for the purpose of comparing the CPU times involved. The appendix contains an annotated, internally documented listing of the FORTRAN source code for TXYZ20. The FORTRAN source code (total of about 21 kbytes) and sample input and output data files are available in ASCII format using a number of transfer vehicles. These include: standard 8 track magnetic tape (ASCII, density = 1600, record = 80, block = 1600), 5.25-in. (360-kbyte and 1.2-Mbyte) DOS-formatted floppy disks, and electronic mail over the Internet. The sample input and output data files are included so that the user can check the program for proper operation as well as to become acquainted with the setup and use of the code. Users of the TXYZ code will find the updated TXYZ20 code easy to use and should benefit from the more flexible input and the more general treatment of heat sources and heat sinks.

12. KEY WORDS (6 TO 12 ENTRIES; ALPHABETICAL ORDER; CAPITALIZE ONLY PROPER NAMES; AND SEPARATE KEY WORDS BY SEMICOLONS)

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